



FORM HDP-1449 (Based on Form PTO-1449)

PATENT AND TRADEMARK OFFICE
INFORMATION DISCLOSURE CITATION
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Sheet 1 of 1

ATTORNEY DOCKET NO.	SERIAL NO.
4041J-000499DVE	10/651,277
APPLICANT	
Yoshifuma Okabe et al.	
FILING DATE	GROUP
08/28/2003	To be assigned

U.S. PATENT DOCUMENTS

Ref. Desig.	Examiner's Initials	Document Number	Date	Name	Class/ Subclass	(If appropriate) Filing Date
1.	Loke	3,858,238	12/1974	Nakamura et al.	257/591	
2.		3,879,230	04/1975	Nakamura et al.	257/607	
3.		4,751,191	06/1988	Gonsiorawski et al.	438/72	
4.		5,065,216	11/1991	Suzuki et al.	257/517	
5.	↓	5,077,143	12/1991	Barraclough et al.	428/690	
6.	Loke	6,114,193	09/2000	Chang et al.	438/140	

FOREIGN PATENT DOCUMENTS

Ref. Desig.	Examiner's Initials	Document Number	Date	Country	Class/ Subclass	Translation Yes	No
1.							

OTHER DOCUMENTS (including Author, Title, Date, Pertinent Pages, etc.)

Ref. Desig.	Examiner's Initials	
1.		

Examiner:

Loke

Date Considered:

9/19/04

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U.S. PATENT DOCUMENTS						
Ref. Desig.	Examiner's Initials	Document Number	Date	Name	Class/ Subclass	(If appropriate) Filing Date
1.	Loke	4,853,345	8/1989	Himelick		
2.		4,879,250	11/1989	Chan		
3.		4,859,629	8/1989	Reardon et al.		
4.		4,927,784	5/1990	Kazior et al.		
5.		4,931,412	6/1990	Fischer et al.		
6.		4,985,740	1/1991	Shenai et al.		
7.		5,241,862	9/1993	Okabe et al.		
8.	↓	5,333,961	8/1994	Lidow et al.		
9.	Loke	5,689,130	11/1997	Okabe et al.	252/342	

FOREIGN PATENT DOCUMENTS						
Ref. Desig.	Examiner's Initials	Document Number	Date	Country	Class/ Subclass	Translation Yes No
1.	Loke	57-15420	1/1982	JAPAN		
2.	Loke	58-45814	10/1993	JAPAN		
3.	Loke	59-113629	6/1985	JAPAN		
4.	Loke	59-189625	10/1984	JAPAN		
5.	Loke	59-213140	12/1984	JAPAN		
6.	Loke	59-220937	12/1994	JAPAN		
7.	Loke	61-234041	10/1986	JAPAN		
8.	Loke	61-296769	12/1986	JAPAN		
9.	Loke	62-23170	1/1987	JAPAN		

Examiner:	Loke	Date Considered:	9/19/04
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FOREIGN PATENT DOCUMENTS						
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10.	Loke	62-43123	10/1987	JAPAN		
11.	Loke	62-243332	10/1987	JAPAN		
12.	Loke	62-293678	12/1987	JAPAN		
13.	Loke	63-253633	10/1988	JAPAN		
14.	Loke	1-169970	7/1989	JAPAN		
15.	Loke	57-097630	6/1982	JAPAN		

OTHER DOCUMENTS (including Author, Title, Date, Pertinent Pages, etc.)		
Ref. Desig.	Examiner's Initials	
1.	Loke	KRISHNA SHENAI, "Vertical-Power DMOSFET", IEEE Elect. Device Letter, Vol. No. 10, No 3, 1989
2.	Loke	Krishnam Shenai, "Optimally Scaled Low-Voltage Vertical Power MOSFET's for High-Frequency Power Conversion", IEEE Trans. of Elect. Device Vol. 37 No. 4, 1990.
3.	Loke	C.Y. Ting et al., "The Use of Titanium-based Contact Barrier Layers in Silicon Technology", Thin Solid Films, 96(1982) 327-345 Electronics and Optics
4.	Loke	Semiconducotr Devices-Physics and Technology, Jan. 1985 S.M. Sze page 307
5.	Loke	Alvin B. Phillips, "Transitor Engineering and Introduction to Integrated Semiconductor Circuits", page 76
6.	Loke	S. Ogawa et al. "HRTEM and Nno-Scale Micro Analysis of Titanium/Silicon Interfacial Reaction Correleated With Electrical Properties, Extended Abstract.
7.	Loke	Wolf et al. "Silicon Processing For The VLSI Era, Vol. 1: Process Tech.", Lattice Press, 1986.

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OTHER DOCUMENTS (including Author, Title, Date, Pertinent Pages, etc.)		
Ref. Desig.	Examiner's Initials	
8.	Loke	K. Shenai et al. "Characteristics of As-Deposited and Sintered Mo/LPCVD W Contacts to as, B, and P Doped Silicon", 1988 Materials Research Sociest, p. 219-224
9.	Loke	K. Shenai et al. "Blanket LPCVD Tungsten Silicide Technology for Smart Power Applications", IEEE Electron Device Letters, vol. 10, no 6 1989m p. 270-273.
10.	Loke	K. Shenai et al., "High-Performanc Vertical-Power DMOSFET's with Selectively Silicided Gate and Source Regions", IEEE Electron Device Letters, vol. 10, no. 4, 1989,p.153-155
11.	Loke	K. Shenai et al. "Selectively Silicided Vertical Power double-diffused metal-oxide semiconductor field effect transisotrs for high-frequency power switching applications", J. Vac. Sci. Tehcnol. B6(6), 1988, p. 1740-1745.
12.	Loke	H.R. Chang et al. "Self-Aligned UMOSFET's with a Specific On-Resistance of , IEEE Transactions on Electron Devices, vol. ED-34, no. 11, 1987, p. 2329-2334
13.	Loke	K. Shenai et al. "Selectively Silicided Vertical Power DMOSFET's for High-Frequency Power Conversion" Electronics Letters, vol. 25 no. 12, 1989, p. 784-785.
14.	Loke	Webster's II New Riverside University Dictionary, 1984, P,549
15.	Loke	Semiconductot devices and technology, by S.M. Sze, P.38

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